

# **Choice of Material for Sensor: Nanostructured Zinc Oxide**

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## Editorial

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One material that has been in great interest from wide

range of technological field associated with nanotechnology

is zinc oxide (ZnO) [1]. It is an important and versatile

functional material having a wide band gap (3.37 eV) with

large exciton energy (60 meV) at room temperature. The ZnO

wurtzite structure has a hexagonal closed-packed unit cell,

with dimensions a = 3.25 Å and c = 5.12 Å [2]. The structure

can be visualized as Zn<sup>2+</sup> ions in half of the tetrahedral holes

of a hexagonal close-packed oxide lattice; the structure with

the longitudinal axis (c-axis) is shown in Figure 1.

### **Editorial**

To study and develop the fundamentals of the gas sensing mechanism, the semiconducting sensors are modified by simple addition of metals (Al, In, Cu, Sn, Fe, Ru, Pt, Pd, etc.), in the base materials, which is referred as doping. Metal oxides such as ZnO,  $SnO_2$ ,  $Fe_2O_3$ ,  $TiO_2$ ,  $WO_3$  etc. have also been used as gas sensors. Despite these broad studies in the semiconductor sensor area, problems such as poor gas selectivity, inability to detect the trace amount of gas (ppm/ ppb), and degradation of the sensor performance by surface contamination still persist. Thus, there is growing need for nanocrystalline gas sensors with novel properties.



In this crystal structure, both zinc and oxygen ions are coordinated with four ions of the opposite charge with strong ionic binding. Due to the size differential of the ions, the ions fill about 44% of the total volume in a ZnO crystal, and leaving a relatively large free volume.

ZnO is a versatile semiconductor material, which has attracted attention for its wide range of technological

applications such as solar cells [3], luminescent, electrical and acoustic devices and chemical sensors [4]. Semiconducting sensors offer an inexpensive and simple method for monitoring gases. To date, various types of ZnO-based gas sensors, such as thick films [5], thin films [6], nanoparticles [7], nanorods [8] and heterojunctions [9], have been demonstrated. Some dangerous and poisonous gases, e.g., hydrogen, LPG, carbon monoxide and methane, etc., could be

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detected [10]. A wide number of methods have been used to prepare ZnO powders, including, homogeneous precipitation in aqueous solution of  $Zn^{2+}$  cations, solution combustion [11], freeze- drying [12], dc magnetron sputtering [13], chemical growth [14] and sol-gel [15]. ZnO thin films were prepared by various techniques such as sol-gel [16], sputtering [17], laser ablation [18], chemical bath deposition [19] and spray pyrolysis [20].

ZnO is a typical n-type semiconductor, in which the density of holes in the valence band is exceeded by the density of electrons in the conduction band; the major charge carrier in ZnO semiconductors is electrons in the conduction band. The formation of oxygen vacancies leads to a higher electron density; donor bands from vacancies in the band gap lead to a substantial increase in the conductivity of the oxide. There are some drawbacks of sensors based on conventional materials barrowed from market.

- a) Selectivity, sensitivity and stability of sensor are poor.
- b) Sensors were work on higher operating temperature.
- c) More response and recovery time.

To remove these drawbacks, nanostructured zinc oxide is preferred.

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